In Situ Scanning Tunneling Microscopy of Underpotential Deposition of Lead on Cu(100) in Sulfuric Acid Solutions

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In situ scanning tunneling microscopy (STM) has been used to examine underpotential deposition (UPD) of lead at Cu(100) electrode in 0.1 M hydrochloric acid containing 1 mM $Pb(C/O_4)_2$. Figure 1 shows the cyclic voltammogram of Cu(100) electrode in 0.01 M containing 1 mМ $Pb(C/O_4)_2$. HC1 А negative-going potential sweep starting from 0.12 V results in UPD of sub-monolayer of Pb adatoms at -0.1 V and bulk deposition of Pb at -0.15 V. These corresponding oxidative stripping processes occur at -0.05 and -0.15 V, respectively. This result is consistent with those reported by others.^{1,2}

The initial stage of Pb deposition results in well-defined strip patterns running parallel to the <001> direction, which are attributed to the formation of surface alloy with a chemical composition of Pb₃Cu₄. Continuous deposition of Pb atoms induces dealloying, where surface Cu atoms are forced Cu out of the alloyed domains, giving rise to a series of ordered structures of Pb adatoms as the coverage exceeds 0.5. The Pb adlayers are characterized by atomic resolution STM imaging as $c(2 \times 2)$, compressed c(2 × 2), and $(5\sqrt{2} \times \sqrt{2})R45^{\circ}$. Figure 2 presents the atomic resolution of the last structure, featuring alternating straight and zigzag Pb atomic chains. These results are consistent with those observed in an ultrahigh vacuum environment.^{3,}

References:

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Figure 1. Cyclic voltammograms at 5 mV/s of Cu(100) in 0.01 M HCl containing 1 mM Pb(ClO₄)₂.



Figure 2. In situ STM atomic resolution of Cu(001) – $(5\sqrt{2} \times \sqrt{2})R45^\circ$ - Pb. The imaging conditions are 50 mV bias voltage and 10 nA setpoint current.